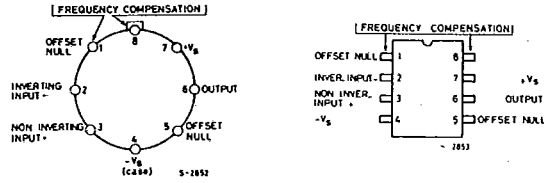


T-79-05-10



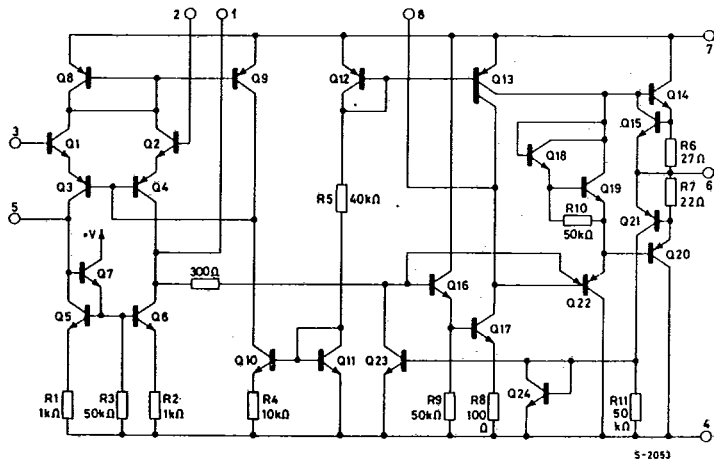
7929225 S G S SEMICONDUCTOR CORP

CONNECTION DIAGRAMS AND ORDERING NUMBERS
(top views)



Type	TO-99	Minidip
LM 748	LM 748H	—
LM 748C	LM 748 CH	LM 748 CN

SCHEMATIC DIAGRAM



THERMAL DATA

$R_{th J-amb}$	Thermal resistance junction-ambient	max	TO-99	Minidip
			155 °C/W	120 °C/W

0234

C-05

196

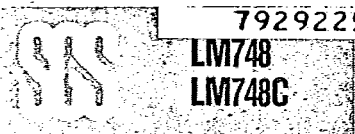


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ELECTRICAL CHARACTERISTICS (see note)

Parameter	Test conditions	LM748			LM748C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V _{os} Input offset voltage	T _{amb} = 25°C R _g ≤ 10 kΩ R _g ≤ 50Ω		1	5		2	6	mV
	T _{amb} = T _{min} to T _{max} R _g ≤ 10 kΩ R _g ≤ 50Ω		1	6			7.5	mV
ΔV _{os} Input offset voltage adjust. range	T _{amb} = 25°C		±15			±15		mV
I _{os} Input offset current	T _{amb} = 25°C		20	200		20	200	nA
	T _{amb} = T _{min} to T _{max}		50	500		300		nA
I _b Input bias current	T _{amb} = 25°C		80	500		80	500	nA
	T _{amb} = T _{min} to T _{max}			1.5		0.8		μA
R _i Input resistance	T _{amb} = 25°C	0.3	2		0.3	2		MΩ
V _i Input voltage range		±12	±13		±12	±13		V
G _v Large signal voltage gain	T _{amb} = 25°C R _L ≥ 2 kΩ V _s = ±15V V _o = ±10V	94	104		86	104		dB
	T _{amb} = T _{min} to T _{max} R _L ≥ 2 kΩ V _s = ±15V V _o = ±10V	88			84			dB
V _o Output voltage swing	V _s = ±15V	±12	±14		±12	±14		V
	R _L ≥ 10 kΩ R _L ≥ 2 kΩ	±10	±13		±10	±13		V
I _{sc} Output short circuit current			25		25			mA
CMR Common mode rejection	R _g ≤ 10 kΩ V _{CM} = ±12V	70	90		70	90		dB
SVR Supply voltage rejection	V _s = ±5 to ±20V R _g ≤ 10 kΩ	76	90		76	90		dB
SR Slew rate	T _{amb} = 25°C R _L ≥ 2 kΩ	G _v = 1	0.5		0.5			V/μs
		G _v = 10*	5.5		5.5			V/μs

* C_c = 3.5 pF



ELECTRICAL CHARACTERISTICS (continued)

Parameter	Test conditions	LM748			LM748C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Transient respon. (unity gain)	$T_{amb} = 25^{\circ}C$ $V_i = 20\text{ mV}$ $C_c = 30\text{ pF}$ $R_L = 2\text{ k}\Omega$ $C_L \leq 100\text{ pF}$							
Rise time			0.2		0.2		μs	
Overshoot			5		5		%	
I_s Supply current	$T_{amb} = 25^{\circ}C$		1.9	2.8	1.9	2.8	mA	
P_s Power consumption	$T_{amb} = 25^{\circ}C$ $V_s = \pm 15V$		60	85	60	85	mW	
	$V_s = \pm 15V$ $T_{amb} = T_{min}$		60	100	60	100	mW	
	$T_{amb} = T_{max}$		45	75			mW	

Note: These specifications, unless otherwise specified, apply for $V_s = \pm 15V$ and $T_{amb} = -55$ to $125^{\circ}C$ for LM748. For LM748C these specifications apply for $T_{amb} = 0$ to $70^{\circ}C$ ($C_c = 30\text{ pF}$).

Fig. 1 - Voltage offset null circuits

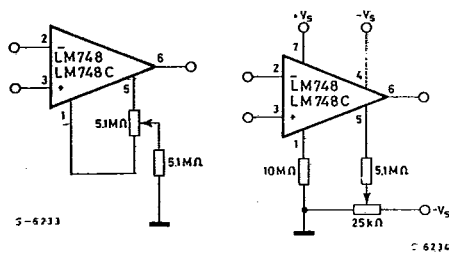
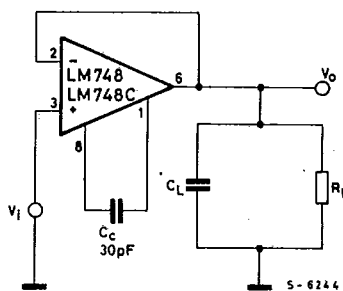
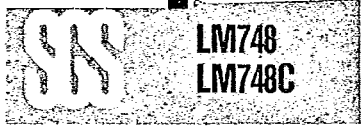


Fig. 2 - Transient response test circuit





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Fig. 3 - Input noise voltage vs. frequency

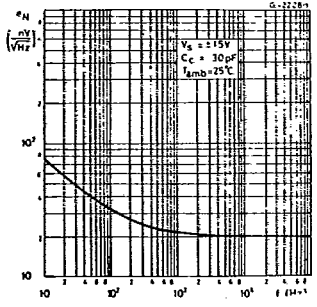


Fig. 4 - Input noise current vs. frequency

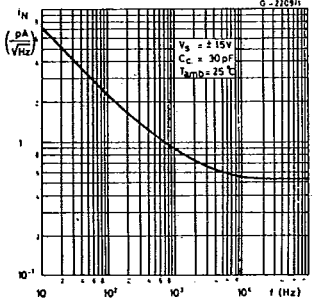


Fig. 5 - Broadband noise for various bandwidths

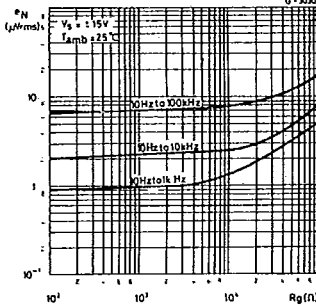


Fig. 6 - Open loop frequency and phase response vs. frequency

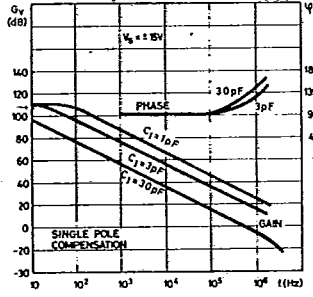


Fig. 7 - Output voltage swing vs. frequency

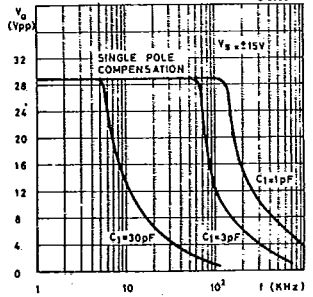


Fig. 8 - Slew-rate

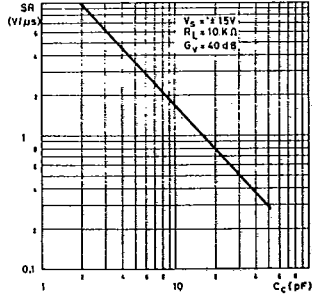


Fig. 9 - Compensation capacitance vs. closed loop voltage gain

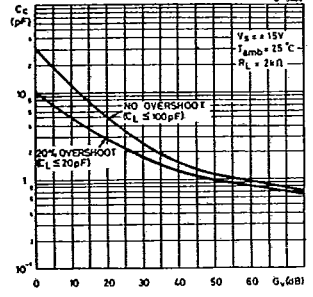


Fig. 10 - Input resistance and input capacitance vs. frequency

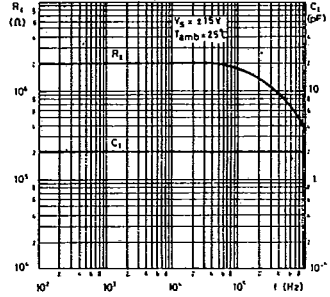


Fig. 11 - Output resistance vs. frequency

